## FM3204/16/64/256

## Integrated Processor Companion with Memory



#### **Features**

#### **High Integration Device Replaces Multiple Parts**

- Serial Nonvolatile Memory
- Low Voltage Reset
- Watchdog Timer
- Early Power-Fail Warning/NMI
- Two 16-bit Event Counters
- Serial Number with Write-lock for Security

## **Processor Companion**

- Active-low Reset Output for V<sub>DD</sub> and Watchdog
- Programmable V<sub>DD</sub> Reset Trip Point
- Manual Reset Filtered and Debounced
- Programmable Watchdog Timer
- Dual Battery-backed Event Counter Tracks System Intrusions or other Events
- Comparator for Early Power-Fail Interrupt
- 64-bit Programmable Serial Number with Lock

#### Ferroelectric Nonvolatile RAM

- 4Kb, 16Kb, 64Kb, and 256Kb versions
- Unlimited Read/Write Endurance
- 10 year Data Retention
- NoDelay<sup>TM</sup> Writes

#### Fast Two-wire Serial Interface

- Up to 1 MHz Maximum Bus Frequency
- Supports Legacy Timing for 100 kHz & 400 kHz
- Device Select Pins for up to 4 Memory Devices
- Companion Controlled via 2-wire Interface

### **Easy to Use Configurations**

- Operates from 2.7 to 5.5V
- Small Footprint 14-pin "Green" SOIC (-G)
- Pin Compatible with FM31xx Series
- Low Operating Current
- -40°C to +85°C Operation

## **Description**

The FM32xx is a family of integrated devices that includes the most commonly needed functions for processor-based systems. Major features include nonvolatile memory available in various sizes, low- $V_{\rm DD}$  reset, watchdog timer, nonvolatile event counter, lockable 64-bit serial number area, and general purpose comparator that can be used for an early power-fail (NMI) interrupt or other purpose. The family operates from 2.7 to 5.5V.

The FM32xx family is software and pinout compatible with the FM31xx family which also includes a real-time clock. The common features allow a system design that easily can be assembled with or without timekeeping by simply selecting the FM31xx or FM32xx, respectively.

Each FM32xx provides nonvolatile RAM available in sizes including 4Kb, 16Kb, 64Kb, and 256Kb versions. Fast write speed and unlimited endurance allow the memory to serve as extra RAM or conventional nonvolatile storage. This memory is truly nonvolatile rather than battery backed.

The processor companion includes commonly needed CPU support functions. Supervisory functions include a reset output signal controlled by either a low  $V_{DD}$  condition or a watchdog timeout. /RST goes active when  $V_{DD}$  drops below a programmable

threshold and remains active for 100 ms after  $V_{\rm DD}$  rises above the trip point. A programmable watchdog timer runs from 100 ms to 3 seconds. The watchdog timer is optional, but if enabled it will assert the reset signal for 100 ms if not restarted by the host before the timeout. A flag-bit indicates the source of the reset.

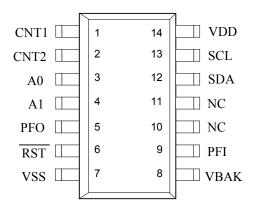
A general-purpose comparator compares an external input pin to the onboard 1.2V reference. This is useful for generating an early warning power-fail interrupt (NMI) but can be used for any purpose. The family also includes a programmable 64-bit serial number that can be locked making it unalterable.

Additionally the FM32xx offers a dual event counter that tracks the number of rising or falling edges detected on dedicated input pins. The counter can optionally be battery backed and even battery operated by attaching a backup power source to the VBAK pin. If VBAK is connected to a battery or capacitor, then events will be counted even in the absence of  $V_{\rm DD}$ .

This product conforms to specifications per the terms of the Ramtron standard warranty. The product has completed Ramtron's internal qualification testing and has reached production status

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## **Pin Configuration**



Pin Name	Function
CNT1, CNT2	Event Counter Inputs
A0, A1	Device Select inputs
PFO	Early Power-fail Output
/RST	Reset Input/Output
PFI	Early Power-fail Input
SDA	Serial Data
SCL	Serial Clock
VBAK	Battery-Backup Supply
VDD	Supply Voltage
VSS	Ground

Ordering Information								
Base Configuration	Memory Size	Operating Voltage	Reset Threshold	Ordering Part Number				
FM32256	256Kb	2.7-5.5V	2.6V, 2.9, 3.9, 4.4V	FM32256-G				
FM3264	64Kb	2.7-5.5V	2.6V, 2.9, 3.9, 4.4V	FM3264-G				
FM3216	16Kb	2.7-5.5V	2.6V, 2.9, 3.9, 4.4V	FM3216-G				
FM3204	4Kb	2.7-5.5V	2.6V, 2.9, 3.9, 4.4V	FM3204-G				

Other memory configurations may be available. Please contact the factory for more information.

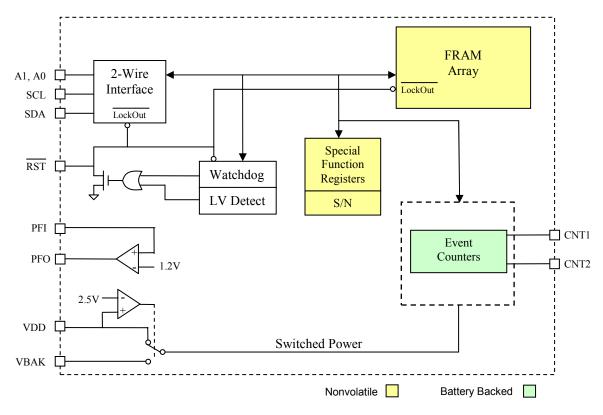


Figure 1. Block Diagram

## **Pin Descriptions**

Pin Name	Type	Pin Description
A0, A1	Input	Device select inputs are used to address multiple memories on a serial bus. To select the device the address value on the two pins must match the corresponding bits contained in the device address. The device select pins are pulled down internally.
CNT1, CNT2	Input	Event Counter Inputs: These battery-backed inputs increment counters when an edge is detected on the corresponding CNT pin. The polarity is programmable. These pins should not be left floating. Tie to ground if pins are not used.
PFO	Output	Power Fail Output: This is the early power-fail output.
/RST	I/O	Active low reset output with weak pull-up. Also input for manual reset.
SDA	I/O	Serial Data & Address: This is a bi-directional line for the two-wire interface. It is open-drain and is intended to be wire-OR'd with other devices on the two-wire bus. The input buffer incorporates a Schmitt trigger for noise immunity and the output driver includes slope control for falling edges. A pull-up resistor is required.
SCL	Input	Serial Clock: The serial clock line for the two-wire interface. Data is clocked out of the part on the falling edge, and in on the rising edge. The SCL input also incorporates a Schmitt trigger input for noise immunity.
PFI	Input	Early Power-fail Input: Typically connected to an unregulated power supply to detect an early power failure. This pin should not be left floating.
VBAK	Supply	Backup supply voltage: A 3V battery or a large value capacitor. If $V_{DD}$ <3.6V and no backup supply is used, this pin should be tied to $V_{DD}$ . If $V_{DD}$ >3.6V and no backup supply is used, this pin should be left floating and the VBC bit should be set.
VDD	Supply	Supply Voltage.
VSS	Supply	Ground

#### Overview

The FM32xx family combines a serial nonvolatile RAM with a processor companion. The companion is a highly integrated peripheral including a processor supervisor, a comparator used for early power-fail warning, nonvolatile event counters, and a 64-bit serial number. The FM32xx integrates these complementary but distinct functions that share a common interface in a single package. Although monolithic, the product is organized as two logical devices, the FRAM memory and the companion. From the system perspective they appear to be two separate devices with unique IDs on the serial bus.

The FM32xx provides the same functions as the FM31xx with the exception of the real-time clock. This makes it easy to develop a common design that can either include timekeeping by using the FM31xx or exclude it by using the FM32xx. All other features are identical. The register address map is even preserved so that software can be identical.

The memory is organized as a stand-alone 2-wire nonvolatile memory with a standard device ID value. The companion functions are accessed under their own 2-wire device ID. This allows the companion functions to be read while maintaining the most recently used memory address. The companion functions are controlled by 16 special function registers. The event counter circuits and related registers are maintained by the power source on the VBAK pin, allowing them to operate from battery or backup capacitor power when  $V_{\rm DD}$  drops below a set threshold. Each functional block is described below.

#### **Memory Operation**

The FM32xx is a family of products available in different memory sizes including 4Kb, 16Kb, 64Kb, and 256Kb. The family is software compatible, all versions use consistent two-byte addressing for the memory device. This makes the lowest density device different from its stand-alone memory counterparts but makes them compatible within the entire family.

Memory is organized in bytes, for example the 4Kb memory is 512 x 8 and the 256Kb memory is 32,768 x 8. The memory is based on FRAM technology. Therefore it can be treated as RAM and is read or written at the speed of the two-wire bus with no delays for write operations. It also offers effectively unlimited write endurance unlike other nonvolatile memory technologies. The 2-wire interface protocol is described further on page 13.

The memory array can be write-protected by software. Two bits in the processor companion area

(WP0, WP1 in register 0Bh) control the protection setting as shown in the following table. Based on the setting, the protected addresses cannot be written and the 2-wire interface will not acknowledge any data to protected addresses. The special function registers containing these bits are described in detail below.

Write protect addresses	WP1	WP0
None	0	0
Bottom 1/4	0	1
Bottom 1/2	1	0
Full array	1	1

## **Processor Companion**

In addition to nonvolatile RAM, the FM32xx family incorporates a highly integrated processor companion. It includes a low voltage reset, a programmable watchdog timer, battery-backed event counters, a comparator for early power-fail detection or other purposes, and a 64-bit serial number.

#### **Processor Supervisor**

Supervisors provide a host processor two basic functions: detection of power supply fault conditions and a watchdog timer to escape a software lockup condition. All FM32xx devices have a reset pin (/RST) to drive the processor reset input during power faults (and power-up) and software lockups. It is an open drain output with a weak internal pull-up to V<sub>DD</sub>. This allows other reset sources to be wire-OR'd to the /RST pin. When V<sub>DD</sub> is above the programmed trip point, /RST output is pulled weakly to V<sub>DD</sub>. If V<sub>DD</sub> drops below the reset trip point voltage level (V<sub>TP</sub>) the /RST pin will be driven low. It will remain low until V<sub>DD</sub> falls too low for circuit operation which is the  $V_{RST}$  level. When  $V_{DD}$  rises again above V<sub>TP</sub>, /RST will continue to drive low for at least 100 ms (t<sub>RPU</sub>) to ensure a robust system reset at a reliable  $V_{DD}$  level. After  $t_{RPU}$  has been met, the /RST pin will return to the weak high state. While /RST is asserted, serial bus activity is locked out even if a transaction occurred as  $V_{DD}$  dropped below  $V_{TP}$ . A memory operation started while  $V_{DD}$  is above  $V_{TP}$ will be completed internally.

Figure 2 below illustrates the reset operation in response to the  $V_{DD}$  voltage.

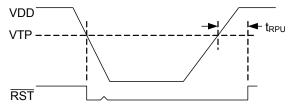


Figure 2. Low Voltage Reset

The bits VTP1 and VTP0 control the trip point of the low voltage detect circuit. They are located in register 0Bh, bits 1 and 0.

$\underline{V}_{TP}$	VTP1	VTP0
$2.\overline{6}V$	0	0
2.9V	0	1
3.9V	1	0
4.4V	1	1

The watchdog timer can also be used to assert the reset signal (/RST). The watchdog is a free running programmable timer. The period can be software programmed from 100 ms to 3 seconds in 100 ms increments via a 5-bit nonvolatile register. All programmed settings are minimum values and vary with temperature according to the operating specifications. The watchdog has two additional controls associated with its operation, a watchdog enable bit (WDE) and timer restart bits (WR). Both the enable bit must be set and the watchdog must timeout in order to drive /RST active. If a reset event occurs, the timer will automatically restart on the rising edge of the reset pulse. If not enabled, the watchdog timer runs but has no effect on /RST. Note that setting the maximum timeout setting (11111b) disables the counter to save power. The second control is a nibble that restarts the timer preventing a reset. The timer should be restarted after changing the timeout value.

The watchdog timeout value is located in register 0Ah, bits 4-0, and the watchdog enable is bit 7. The watchdog is restarted by writing the pattern 1010b to the lower nibble of register 09h. Writing this pattern will also cause the timer to load new timeout values. Writing other patterns to this address will not affect its operation. Note the watchdog timer is freerunning. Prior to enabling it, users should restart the timer as described above. This assures that the full timeout period will be set immediately after enabling. The watchdog is disabled when  $V_{\rm DD}$  is below  $V_{\rm TP}$ . The following table summarizes the watchdog bits. A block diagram follows.

Watchdog timeout WDT4-0 0Ah, bits 4-0 Watchdog enable WDE 0Ah, bit 7 Watchdog restart WR3-0 09h, bits 3-0

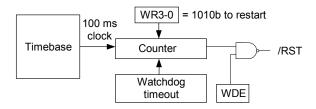


Figure 3. Watchdog Timer

#### **Manual Reset**

The /RST pin is bi-directional and allows the FM32xx to filter and de-bounce a manual reset switch. The /RST input detects an external low condition and responds by driving the /RST signal low for 100 ms.

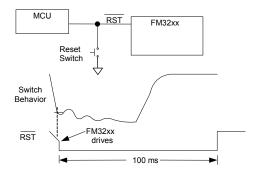


Figure 4. Manual Reset

Note that an internal weak pull-up on /RST eliminates the need for additional external components.

#### **Reset Flags**

In case of a reset condition, a flag will be set to indicate the source of the reset. A low  $V_{\rm DD}$  reset is indicated by the POR flag, register 09h bit 6. A watchdog reset is indicated by the WTR flag, register 09h bit 7. Note that the flags are internally set in response to reset sources, but they must be cleared by the user. When the register is read, it is possible that both flags are set if both have occurred since the user last cleared them.

#### **Early Power Fail Comparator**

An early power fail warning can be provided to the processor well before  $V_{\rm DD}$  drops out of spec. The comparator is used to create a power fail interrupt (NMI). This can be accomplished by connecting the PFI pin to the unregulated power supply via a resistor divider. An application circuit is shown below.

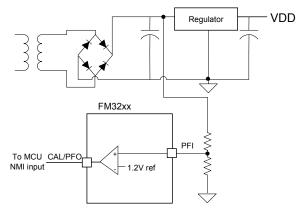


Figure 5. Comparator as Early Power-Fail Warning

The voltage on the PFI input pin is compared to an onboard 1.2V reference. When the PFI input voltage drops below this threshold, the comparator will drive the PFO pin to a low state. The comparator has 100 mV (max) of hysteresis to reduce noise sensitivity, only for a rising PFI signal. For a falling PFI edge, there is no hysteresis.

The comparator is a general purpose device and its application is not limited to the NMI function.

Note: The maximum voltage on the comparator input PFI is limited to 3.75V under normal operating conditions.

#### **Event Counter**

The FM32xx offers the user two battery-backed event counters. Input pins CNT1 and CNT2 are programmable edge detectors. Each clocks a 16-bit counter. When an edge occurs, the counters will increment their respective registers. Counter 1 is located in registers 0Dh and 0Eh, Counter 2 is located in registers 0Fh and 10h. These register values can be read anytime  $V_{\text{DD}}$  is above  $V_{\text{TP}}$ , and they will be incremented as long as a valid VBAK power source is provided. To read, set the RC bit register 0Ch bit 3 to 1. This takes a snapshot of all four counter bytes allowing a stable value even if a count occurs during the read. The registers can be written by software allowing the counters to be cleared or initialized by the system. Counts are blocked during a write operation. The two counters can be cascaded to create a single 32-bit counter by setting the CC control bit (register 0Ch). When cascaded, the CNT1 input will cause the counter to increment. CNT2 is not used in this mode.

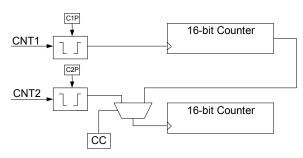


Figure 6. Event Counter

The control bits for event counting are located in register 0Ch. Counter 1 Polarity is bit C1P, bit 0; Counter 2 Polarity is C2P, bit 1; the Cascade Control is CC, bit 2; and the Read Counter bit is RC bit 3.

The polarity bits must be set prior to setting the counter value(s). If a polarity bit is changed, the

counter may inadvertently increment. If the counter pins are not being used, tie them to ground.

#### **Serial Number**

A memory location to write a 64-bit serial number is provided. It is a writeable nonvolatile memory block that can be locked by the user once the serial number is set. The 8 bytes of data and the lock bit are all accessed via the device ID for the processor companion. Therefore the serial number area is separate and distinct from the memory array. The serial number registers can be written an unlimited number of times, so these locations are general purpose memory. However once the lock bit is set the values cannot be altered and the lock cannot be removed. Once locked the serial number registers can still be read by the system.

The serial number is located in registers 11h to 18h. The lock bit is SNL, register 0Bh bit 7. Setting the SNL bit to a 1 disables writes to the serial number registers, and *the SNL bit cannot be cleared*.

#### **Backup Power**

The event counter and battery-backed registers may be powered with a backup power source. When the primary system power fails, the voltage on the  $V_{DD}$  pin will drop. When  $V_{DD}$  is less than 2.5V, the event counters and battery-backed registers will switch to the backup power supply on  $V_{BAK}$ .

### Trickle Charger

To facilitate capacitor backup the  $V_{BAK}$  pin can optionally provide a trickle charge current. When the VBC bit, register 0Bh bit 2, is set to 1 the  $V_{BAK}$  pin will source approximately 15  $\mu$ A until  $V_{BAK}$  reaches  $V_{DD}$  or 3.75V whichever is less. In 3V systems, this charges the capacitor to  $V_{DD}$  without an external diode and resistor charger. In 5V systems, it provides the same convenience and also prevents the user from exceeding the  $V_{BAK}$  maximum voltage specification.

In the case where no battery is used, the  $V_{BAK}$  pin should be tied according to the following conditions:

- For 3.3V systems,  $V_{BAK}$  should be tied to  $V_{DD}$ . This assumes  $V_{DD}$  does not exceed 3.75V.
- For 5V systems, attach a 1  $\mu$ F capacitor to  $V_{BAK}$  and turn the trickle charger on. The  $V_{BAK}$  pin will charge to the internal backup voltage which regulates itself to about 3.6V.  $V_{BAK}$  should not be tied to 5V since the  $V_{BAK}$  (max) specification will be exceeded. A 1  $\mu$ F capacitor will keep the companion functions working for about 1.5 second.

Although  $V_{BAK}$  may be connected to  $V_{SS}$ , this is not recommended if the companion is used. None of the companion functions will operate below about 2.5V.

 ${\mathfrak V}$  Note: systems using lithium batteries should clear the VBC bit to 0 to prevent battery charging. The  $V_{BAK}$  circuitry includes an internal 1  $K\Omega$  series resistor as a safety element.

## **Register Map**

The processor companion functions are accessed via 16 special function registers that are mapped to a separate 2-wire device ID. The interface protocol is described below. The registers contain control bits, or information flags. A description of each register follows.

### **Register Map Summary Table**

Nonvolatile = Battery-backed =

			1							
Address	S D7 D6 D5 D4 D3 D2 D1 D0								Function	Range
18h			Seria	al Number B	Byte 7				Serial Number 7	FFh
17h			Seria	al Number B	Byte 6				Serial Number 6	FFh
16h			Seria	al Number B	Byte 5				Serial Number 5	FFh
15h			Seria	al Number B	Byte 4				Serial Number 4	FFh
14h			Seria	al Number B	Byte 3				Serial Number 3	FFh
13h			Seria	al Number B	Byte 2				Serial Number 2	FFh
12h			Seria	al Number B	Byte 1				Serial Number 1	FFh
11h			Seria	al Number B	Byte 0				Serial Number 0	FFh
10h			С	ounter 2 MS	SB				Event Counter 2 MSB	FFh
0Fh			C	ounter 2 LS	SB				Event Counter 2 LSB	FFh
0Eh			С	ounter 1 MS	SB				Event Counter 1 MSB	FFh
0Dh			C	ounter 1 LS	SB				Event Counter 1 LSB	FFh
0Ch	-	-	-	-	RC	CC	C2P	C1P	Event Count Control	
0Bh	SNL	-	-	WP1	WP0	VBC	VTP1	VTP0	Companion Control	
0Ah	WDE	-	WDT0	Watchdog Control						
09h	WTR	POR	LB	-	WR3	WR2	WR1	WR0	Watchdog Restart/Flag	s
00-08h				DO NO	OT USE				RESERVED	

<sup>\*</sup>Note that the usable address range starts at address 09h to preserve software compatibility with the FM31xx device family, which includes a real-time clock in registers 00-08h.

Note: When the device is first powered up and programmed, all registers must be written because the battery-backed register values cannot be guaranteed. The table below shows the default values of the non-volatile registers. All other register values should be treated as unknown.

**Default Register Values** 

Address	Hex Value
18h	0x00
17h	0x00
16h	0x00
15h	0x00
14h	0x00
13h	0x00
12h	0x00
11h	0x00
0Bh	0x00
0Ah	0x1F

## Register Description Address Description

18h	Serial Num	ber Byte 7						
	D7	D6	D5	D4	D3	D2	D1	D0
	SN.63	SN.62	SN.61	SN.60	SN.59	SN.58	SN.57	SN.56
	Upper byte o	f the serial nur	nber. Read/wri	te when SNL=	), read-only wh	nen SNL=1. No	onvolatile.	
17h	Serial Num	iber Byte 6						
	<b>D</b> 7	D6	D5	D4	D3	D2	D1	D0
	SN.55	SN.54	SN.53	SN.52	SN.51	SN.50	SN.49	SN.48
	Byte 6 of the	serial number.	. Read/write wl	hen SNL=0, rea	ad-only when S	SNL=1. Nonvo	latile.	
16h	Serial Num							
	<b>D</b> 7	D6	D5	D4	D3	D2	D1	D0
	SN.47	SN.46	SN.45	SN.44	SN.43	SN.42	SN.41	SN.40
			. Read/write wl	hen SNL=0, rea	ad-only when S	SNL=1. Nonvo	latile.	
15h	Serial Num	ber Byte 4						
	<b>D</b> 7	D6	D5	D4	D3	D2	D1	D0
	SN.39	SN.38	SN.37	SN.36	SN.35	SN.34	SN.33	SN.32
	Byte 4 of the			hen SNL=0, rea	ad-only when S	SNL=1. Nonvo	latile.	
14h	Serial Num	ber Byte 3						
	<b>D</b> 7	D6	D5	D4	D3	D2	D1	D0
	SN.31	SN.30	SN.29	SN.28	SN.27	SN.26	SN.25	SN.24
				hen SNL=0, rea				
13h	Serial Num			•				
	D7	D6	D5	D4	D3	D2	D1	D0
	SN.23	SN.22	SN.21	SN.20	SN.19	SN.18	SN.17	SN.16
				hen SNL=0, rea				511.10
12h	Serial Num			,	<u> </u>			
								1
	<b>D</b> 7	D6	D5	D4	D3	D2	D1	<b>D0</b>
	D7 SN.15	D6 SN.14	D5 SN.13	D4 SN.12	D3 SN.11	D2 SN.10		
	SN.15	SN.14	SN.13		SN.11	SN.10	SN.9	D0 SN.8
11h	SN.15	SN.14 serial number.	SN.13	SN.12	SN.11	SN.10	SN.9	
11h	SN.15 Byte 1 of the	SN.14 serial number.	SN.13	SN.12	SN.11	SN.10	SN.9	
11h	SN.15  Byte 1 of the  Serial Num  D7	SN.14 serial number. ber Byte 0 D6	SN.13  Read/write wl	SN.12 hen SNL=0, rea	SN.11 ad-only when S	SN.10 SNL=1. Nonvo	SN.9 latile.	SN.8  D0
11h	SN.15 Byte 1 of the Serial Num D7 SN.7	SN.14 serial number. ber Byte 0 D6 SN.6	SN.13 Read/write wl	SN.12 hen SNL=0, rea D4 SN.4	SN.11 ad-only when S  D3  SN.3	SN.10 SNL=1. Nonvo D2 SN.2	SN.9 latile.  D1 SN.1	SN.8
	SN.15 Byte 1 of the Serial Num D7 SN.7 LSB of the so	SN.14 serial number. ber Byte 0 D6 SN.6 erial number. R	SN.13 Read/write wl	SN.12 hen SNL=0, rea	SN.11 ad-only when S  D3  SN.3	SN.10 SNL=1. Nonvo D2 SN.2	SN.9 latile.  D1 SN.1	SN.8  D0
11h	SN.15 Byte 1 of the Serial Num D7 SN.7	SN.14 serial number. ber Byte 0 D6 SN.6 erial number. R	SN.13 Read/write wl	SN.12 hen SNL=0, rea D4 SN.4	SN.11 ad-only when S  D3  SN.3	SN.10 SNL=1. Nonvo D2 SN.2	SN.9 latile.  D1 SN.1	SN.8  D0
	SN.15 Byte 1 of the Serial Num D7 SN.7 LSB of the so Counter 2	SN.14 serial number. ber Byte 0 D6 SN.6 erial number. R MSB D6	SN.13  Read/write wl  D5  SN.5  Read/write whe	SN.12 hen SNL=0, rea  D4 SN.4 n SNL=0, read  D4	SN.11 ad-only when S  D3 SN.3 -only when SN	SN.10 SNL=1. Nonvo  D2 SN.2 IL=1. Nonvola  D2	SN.9 latile.  D1 SN.1 tile.	SN.8  D0  SN.0
	SN.15 Byte 1 of the Serial Num D7 SN.7 LSB of the so Counter 2 D7 C2.15	SN.14 serial number. ber Byte 0 D6 SN.6 erial number. R MSB D6 C2.14	SN.13  Read/write wl  D5  SN.5  Read/write whe  D5  C2.13	SN.12 hen SNL=0, rea  D4 SN.4 n SNL=0, read  D4 C2.12	SN.11 ad-only when S  D3 SN.3 -only when SN  D3 C2.11	SN.10 SNL=1. Nonvo  D2 SN.2 IL=1. Nonvola  D2 C2.10	SN.9 latile.  D1 SN.1 tile.  D1 C2.9	SN.8  D0  SN.0
10h	SN.15 Byte 1 of the Serial Num D7 SN.7 LSB of the so Counter 2 D7 C2.15 Event Counter	SN.14 serial number. ber Byte 0 D6 SN.6 erial number. R MSB D6 C2.14 er 2 MSB. Incr	SN.13  Read/write wl  D5  SN.5  Read/write whe  D5  C2.13	SN.12 hen SNL=0, rea  D4 SN.4 n SNL=0, read  D4	SN.11 ad-only when S  D3 SN.3 -only when SN  D3 C2.11	SN.10 SNL=1. Nonvo  D2 SN.2 IL=1. Nonvola  D2 C2.10	SN.9 latile.  D1 SN.1 tile.  D1 C2.9	SN.8  D0  SN.0
	SN.15 Byte 1 of the Serial Num D7 SN.7 LSB of the so Counter 2 D7 C2.15	SN.14 serial number. ber Byte 0 D6 SN.6 erial number. R MSB D6 C2.14 er 2 MSB. Incr	SN.13  Read/write wl  D5  SN.5  Read/write whe  D5  C2.13	SN.12 hen SNL=0, rea  D4 SN.4 n SNL=0, read  D4 C2.12	SN.11 ad-only when S  D3 SN.3 -only when SN  D3 C2.11	SN.10 SNL=1. Nonvo  D2 SN.2 IL=1. Nonvola  D2 C2.10	SN.9 latile.  D1 SN.1 tile.  D1 C2.9	SN.8  D0  SN.0
10h	SN.15 Byte 1 of the Serial Num D7 SN.7 LSB of the so Counter 2 D7 C2.15 Event Counter Counter 2 D7	SN.14 serial number. ber Byte 0 D6 SN.6 erial number. R MSB D6 C2.14 er 2 MSB. Incr LSB D6	SN.13 Read/write wl  D5 SN.5 Read/write whe  D5 C2.13 ements on over	SN.12 hen SNL=0, rea  D4 SN.4 n SNL=0, read  D4 C2.12 rflows from Co	SN.11 ad-only when S  D3 SN.3 -only when SN  D3 C2.11 unter 2 LSB. E	SN.10 SNL=1. Nonvo  D2 SN.2 IL=1. Nonvola  D2 C2.10 Battery-backed,	SN.9 latile.  D1 SN.1 tile.  D1 C2.9 read/write.	D0 SN.0  D0 C2.8
10h	SN.15 Byte 1 of the Serial Num D7 SN.7 LSB of the so Counter 2 D7 C2.15 Event Counter Counter 2 D7 C2.7	SN.14 serial number. ber Byte 0 D6 SN.6 erial number. R MSB D6 C2.14 er 2 MSB. Incr LSB D6 C2.6	SN.13 Read/write wl  D5 SN.5 Read/write whe  D5 C2.13 ements on over	SN.12 hen SNL=0, rea  D4 SN.4 n SNL=0, read  D4 C2.12 rflows from Co  D4 C2.4	SN.11 ad-only when S  D3 SN.3 -only when SN  D3 C2.11 unter 2 LSB. E  D3 C2.3	SN.10 SNL=1, Nonvo  D2 SN.2 IL=1, Nonvola  D2 C2.10 Battery-backed, D2 C2.2	SN.9 latile.  D1 SN.1 tile.  D1 C2.9 read/write.  D1 C2.1	D0 SN.0  D0 C2.8  D0 C2.0
10h	SN.15 Byte 1 of the Serial Num D7 SN.7 LSB of the so Counter 2 D7 C2.15 Event Counter Counter 2 D7 C2.7 Event Counter	SN.14 serial number. ber Byte 0 D6 SN.6 erial number. R MSB D6 C2.14 er 2 MSB. Incre LSB D6 C2.6 er 2 LSB. Incre	SN.13 Read/write wl  D5 SN.5 Read/write whe  D5 C2.13 ements on over	SN.12 hen SNL=0, rea  D4 SN.4 n SNL=0, read  D4 C2.12 rflows from Co	SN.11 ad-only when S  D3 SN.3 -only when SN  D3 C2.11 unter 2 LSB. E  D3 C2.3	SN.10 SNL=1, Nonvo  D2 SN.2 IL=1, Nonvola  D2 C2.10 Battery-backed, D2 C2.2	SN.9 latile.  D1 SN.1 tile.  D1 C2.9 read/write.  D1 C2.1	D0 SN.0  D0 C2.8  D0 C2.0
10h 0Fh	SN.15 Byte 1 of the Serial Num D7 SN.7 LSB of the so Counter 2 D7 C2.15 Event Counter Counter 2 D7 C2.7 Event Counter when CC=1.	SN.14 serial number. ber Byte 0 D6 SN.6 erial number. R MSB D6 C2.14 er 2 MSB. Incre LSB D6 C2.6 er 2 LSB. Incre Battery-backet	SN.13 Read/write wl  D5 SN.5 Read/write whe  D5 C2.13 ements on over	SN.12 hen SNL=0, rea  D4 SN.4 n SNL=0, read  D4 C2.12 rflows from Co  D4 C2.4	SN.11 ad-only when S  D3 SN.3 -only when SN  D3 C2.11 unter 2 LSB. E  D3 C2.3	SN.10 SNL=1, Nonvo  D2 SN.2 IL=1, Nonvola  D2 C2.10 Battery-backed, D2 C2.2	SN.9 latile.  D1 SN.1 tile.  D1 C2.9 read/write.  D1 C2.1	D0 SN.0  D0 C2.8  D0 C2.0
10h	SN.15 Byte 1 of the Serial Num D7 SN.7 LSB of the so Counter 2 D7 C2.15 Event Counter Counter 2 D7 C2.7 Event Counter	SN.14 serial number. ber Byte 0 D6 SN.6 erial number. R MSB D6 C2.14 er 2 MSB. Incre LSB D6 C2.6 er 2 LSB. Incre Battery-backet	SN.13 Read/write wl  D5 SN.5 Read/write whe  D5 C2.13 ements on over	SN.12 hen SNL=0, rea  D4 SN.4 n SNL=0, read  D4 C2.12 rflows from Co  D4 C2.4	SN.11 ad-only when S  D3 SN.3 -only when SN  D3 C2.11 unter 2 LSB. E  D3 C2.3	SN.10 SNL=1, Nonvo  D2 SN.2 IL=1, Nonvola  D2 C2.10 Battery-backed, D2 C2.2	SN.9 latile.  D1 SN.1 tile.  D1 C2.9 read/write.  D1 C2.1	D0 SN.0  D0 C2.8  D0 C2.0
10h 0Fh	SN.15 Byte 1 of the Serial Num D7 SN.7 LSB of the so Counter 2 D7 C2.15 Event Counter 2 D7 C2.7 Event Counter 2 D7 C2.7 Event Counter 1 D7	SN.14 serial number. ber Byte 0 D6 SN.6 erial number. R MSB D6 C2.14 er 2 MSB. Incr LSB D6 C2.6 er 2 LSB. Incre Battery-backer MSB D6	SN.13 Read/write wl  D5 SN.5 Read/write whe  D5 C2.13 ements on over  D5 C2.5 ements on progd, read/write .	SN.12 hen SNL=0, rea  D4 SN.4 n SNL=0, read  D4 C2.12 rflows from Co  D4 C2.4 rammed edge e	SN.11 ad-only when S  D3 SN.3 -only when SN  D3 C2.11 unter 2 LSB. E  D3 C2.3 event on CNT2	SN.10 SNL=1. Nonvo  D2 SN.2 IL=1. Nonvola  D2 C2.10 Battery-backed,  D2 C2.2 input or overf	SN.9 latile.  D1 SN.1 tile.  D2.9 read/write.  D1 C2.1 lows from Cou	D0 SN.0  D0 C2.8  D0 C2.0  nter 1 MSB
10h 0Fh	SN.15 Byte 1 of the Serial Num D7 SN.7 LSB of the sc Counter 2 D7 C2.15 Event Counter 2 D7 C2.7 Event Counter 1 D7 C1.15	SN.14 serial number. ber Byte 0 D6 SN.6 erial number. R MSB D6 C2.14 er 2 MSB. Incr LSB D6 C2.6 er 2 LSB. Incre Battery-backer MSB D6 C1.14	SN.13 Read/write wl  D5 SN.5 Read/write whe  D5 C2.13 ements on over  D5 C2.5 ements on progd, read/write .  D5 C1.13	SN.12 hen SNL=0, rea  D4 SN.4 n SNL=0, read  D4 C2.12 rflows from Co  D4 C2.4 rammed edge e	SN.11 ad-only when S  D3 SN.3 -only when SN  D3 C2.11 unter 2 LSB. E  D3 C2.3 event on CNT2  D3 C1.11	SN.10 SNL=1. Nonvo  D2 SN.2 IL=1. Nonvola  D2 C2.10 Battery-backed,  D2 C2.2 input or overf	SN.9 latile.  D1 SN.1 tile.  D1 C2.9 read/write.  D1 C2.1 lows from Cou	D0 SN.0  D0 C2.8  D0 C2.0  nter 1 MSB
10h  OFh  OEh	SN.15 Byte 1 of the Serial Num D7 SN.7 LSB of the so Counter 2 D7 C2.15 Event Counter 2 D7 C2.7 Event Counter 1 D7 C1.15 Event Counter 1 D7	SN.14 serial number. ber Byte 0 D6 SN.6 erial number. R MSB D6 C2.14 er 2 MSB. Incre LSB C2.6 er 2 LSB. Incre Battery-backer MSB D6 C1.14 er 1 MSB. Incre	SN.13 Read/write wl  D5 SN.5 Read/write whe  D5 C2.13 ements on over  D5 C2.5 ements on progd, read/write .  D5 C1.13	SN.12 hen SNL=0, rea  D4 SN.4 n SNL=0, read  D4 C2.12 rflows from Co  D4 C2.4 rammed edge e	SN.11 ad-only when S  D3 SN.3 -only when SN  D3 C2.11 unter 2 LSB. E  D3 C2.3 event on CNT2  D3 C1.11	SN.10 SNL=1. Nonvo  D2 SN.2 IL=1. Nonvola  D2 C2.10 Battery-backed,  D2 C2.2 input or overf	SN.9 latile.  D1 SN.1 tile.  D1 C2.9 read/write.  D1 C2.1 lows from Cou	D0 SN.0  D0 C2.8  D0 C2.0  nter 1 MSB
10h 0Fh	SN.15 Byte 1 of the Serial Num D7 SN.7 LSB of the sc Counter 2 D7 C2.15 Event Counter 2 D7 C2.7 Event Counter 1 D7 C1.15	SN.14 serial number. ber Byte 0 D6 SN.6 erial number. R MSB D6 C2.14 er 2 MSB. Incre LSB D6 c2.6 er 2 LSB. Incre Battery-backer MSB D6 C1.14 er 1 MSB. Incre LSB	SN.13 Read/write wl  D5 SN.5 Read/write whe  D5 C2.13 ements on over  D5 c2.5 ements on progd, read/write .  D5 C1.13 ements on over	SN.12 hen SNL=0, rea  D4 SN.4 n SNL=0, read  D4 C2.12 rflows from Co  D4 C2.4 rammed edge e	SN.11 ad-only when S  D3 SN.3 -only when SN  D3 C2.11 unter 2 LSB. F  D3 C2.3 event on CNT2  D3 C1.11 unter 1 LSB. F	SN.10 SNL=1. Nonvo  D2 SN.2 IL=1. Nonvola  D2 C2.10 Battery-backed,  D2 C2.2 input or overf	SN.9 latile.  D1 SN.1 tile.  D1 C2.9 read/write.  D1 C2.1 lows from Cou	D0 SN.0  D0 C2.8  D0 C2.0  nter 1 MSB
10h  OFh  OEh	SN.15 Byte 1 of the Serial Num D7 SN.7 LSB of the se Counter 2 D7 C2.15 Event Counter Counter 2 D7 C2.7 Event Counter by Counter 1 D7 C1.15 Event Counter Counter 1 D7 C1.15 Event Counter Counter 1 D7	SN.14 serial number. ber Byte 0 D6 SN.6 erial number. R MSB D6 C2.14 er 2 MSB. Incre LSB D6 C2.6 er 2 LSB. Incre Battery-backer MSB D6 C1.14 er 1 MSB. Incre LSB D6 C1.14 er 1 MSB. Incre LSB	SN.13 Read/write wl D5 SN.5 Read/write whe D5 C2.13 ements on over D5 C2.5 ements on prog d, read/write .  D5 C1.13 ements on over	SN.12 hen SNL=0, read  D4 SN.4 n SNL=0, read  D4 C2.12 rflows from Co  D4 C2.4 rammed edge e  D4 C1.12 rflows from Co	SN.11 ad-only when S  D3 SN.3 -only when SN  D3 C2.11 unter 2 LSB. E  D3 C2.3 event on CNT2  D3 C1.11 unter 1 LSB. E	SN.10 SNL=1. Nonvo  D2 SN.2 IL=1. Nonvola  D2 C2.10 Battery-backed  D2 C2.2 input or overf  D2 C1.10 Battery-backed,	SN.9 latile.  D1 SN.1 tile.  D2.9 read/write.  D1 C2.1 lows from Cou D1 C1.9 read/write.  D1	D0 SN.0  D0 C2.8  D0 C2.0  nter 1 MSB  D0 C1.8
10h 0Fh 0Eh	SN.15 Byte 1 of the Serial Num D7 SN.7 LSB of the se Counter 2 D7 C2.15 Event Counter Counter 2 D7 C2.7 Event Counter when CC=1. Counter 1 D7 C1.15 Event Counter Counter 1 D7 C1.7	SN.14 serial number. ber Byte 0 D6 SN.6 erial number. R MSB D6 C2.14 er 2 MSB. Incre LSB D6 C2.6 er 2 LSB. Incre Battery-backer MSB D6 C1.14 er 1 MSB. Incre LSB C1.6 C1.6	SN.13  Read/write wl  D5 SN.5 Read/write whe  D5 C2.13 ements on over  D5 C2.5 ements on progd, read/write .  D5 C1.13 ements on over	SN.12 hen SNL=0, rea  D4 SN.4 n SNL=0, read  D4 C2.12 rflows from Co  D4 C2.4 rammed edge e  D4 C1.12 rflows from Co	SN.11 ad-only when S  D3 SN.3 -only when SN  D3 C2.11 unter 2 LSB. E  D3 C2.3 event on CNT2  D3 C1.11 unter 1 LSB. E  D3 C1.3	SN.10 SNL=1. Nonvo  D2 SN.2 IL=1. Nonvola  D2 C2.10 Battery-backed  D2 C2.2 input or overf  D2 C1.10 Battery-backed,  D2 C1.10 C1.2	SN.9 latile.  D1 SN.1 tile.  D1 C2.9 read/write.  D1 C1.9 read/write.  D1 C1.9 read/write.	D0 SN.0  D0 C2.8  D0 C2.0  nter 1 MSB  D0 C1.8

0Ch	Event Co	unter Conti	-al							
UCII	D7	D6	D5	D4	D3	D2	D1	D0		
						CC	C2P			
RC	Read Coun	ter Setting th	is bit to 1 takes	a snapshot of t	he four counter	s bytes allowin		C1P read the		
i i i		values without missing count events. The RC bit will be automatically cleared.								
CC	Counter Ca	ascade. When	CC=0, the even	nt counters oper	ate independer	tly according to				
	C1P and C2P respectively. When CC=1, the counters are cascaded to create one 32-bit counter. The registers of Counter 2 represent the most significant 16-bits of the counter and CNT1 is the controlling input. Bit C2P is									
					counter and CN	T1 is the contro	olling input. Bit	C2P 1S		
C2P			Battery-backe		when C2P = 1	. C2P is "don't	care" when CC	=1 The value		
C21	of Event C	ounter 2 may	inadvertently in	crement if C2P	is changed. B	attery-backed, r	ead/write.	1. The value		
C1P	CNT1 dete	ects falling edg	ges when C1P =	0, rising edges	when $C1P = 1$	. The value of I		may		
			if C1P is change	ed. Battery-bac	ked, read/write					
0Bh		on Control								
	D7	D6	D5	D4	D3	D2	D1	D0		
	SNL	-	-	WP1	WP0	VBC	VTP1	VTP0		
SNL					to 18h and SN	L permanently	read-only. SNI	L cannot be		
WP1-0			Ionvolatile, reac		the memory a	rray. Nonvolati	e read/write			
W1 1-0	WIILE I IOU	ect. These ons	control the wil	te protection of	the memory a	iray. Noiivoiatii	ie, read/write.			
	7	Write protect	addresses	WP1 WP0	<u>)</u>					
	l l	None		0 0						
		Bottom 1/4		0 1						
		Bottom 1/2		1 0						
T/D/C		Full array	C w ADC	1 1	A / : 11 1	1	1: 1 37	DAIZ		
VBC			les the charge c			rge current to be	e supplied on V	BAK.		
VTP1-0						t function. Non	volatile_read/w	rite		
, , , , ,										
	_	VTP	VTP1 V	<u>ΓΡ0</u>						
		2.6V		0						
		2.9V	0	1						
		3.9V 1.4V	1	0						
0Ah	-		1	1						
UAN	D7	g Control D6	D5	D4	D3	D2	D1	D0		
		Du	<b>D</b> 3							
WDE	Watchdog	Enable When	WDE-1 the w	WDT4	WDT3	WDT2 RST signal to go	WDT1	WDF = 0 the		
WDE	1 -					, users should r				
						occurs. Nonvo				
WDT4-0						l with 100 ms re				
	timeouts ar	re loaded when	n the timer is re	started by writi	ng the 1010b p	attern to WR3-	0. Nonvolatile,	read/write.		
	,	Watchdog tin	neout	WDT4 W	/DT3 WDT2	WDT1 WD7	0			
		nvalid – defa		0	0  0		<u>. v</u> )			
		100 ms		0	0 0	0				
	2	200 ms		0	0 0	1 (	)			
	3	300 ms		0	0 0	1				
		•								
	7	2000 ms		1	0 1	0 (	)			
		2100 ms		1	0 1	0				
		2200 ms		1	0 1		)			
		: 2900 ms		1	1 1	0 1	1			
		2900 ms 3000 ms		1 1	1 1 1 1	0 1				
		Disable coun	ter	1 1	1 1	1 1	<i>,</i> 			
	1	risuote coull	101	1	1 I	1	<u>i</u>			

09h	Watchdo	g Restart &	Flags						
	D7	D6	D5	D4	D2	D1	D0		
	WTR	POR	LB	ı	WR3	WR2	WR1	WR0	
WTR									
POR	cleared by	the user. Note	that both WTR	n is activated b and POR could l. Read/Write (	d be set if both	reset sources ha	ave occurred sin		
LB	were cleared by the user. Battery-backed. Read/Write (internally set, user can clear bit).  Low Backup Flag: On power up, if the VBAK source is below the minimum voltage to operate the event counters, this bit will be set to 1. The user should clear it to 0 when initializing the system. Battery-backed. Read/Write (internally set, user can clear bit).								
WR3-0	not affect t	his operation.	Writing any pa	10b to WR3-0 attern other that ags without affe	n 1010b to WR	3-0 has no effe	ect on the time		

00-08h Reserved – DO NOT USE THIS ADDRESS SPACE

#### **Two-wire Interface**

The FM32xx employs an industry standard two-wire bus that is familiar to many users. This product is unique since it incorporates two logical devices in one chip. Each logical device can be accessed individually. Although monolithic, it appears to the system software to be two separate products. One is a memory device. It has a Slave Address (Slave ID = 1010b) that operates the same as a stand-alone memory device. The second device is a real-time clock and processor companion which have a unique Slave Address (Slave ID = 1101b).

By convention, any device that is sending data onto the bus is the transmitter while the target device for this data is the receiver. The device that is controlling the bus is the master. The master is responsible for generating the clock signal for all operations. Any device on the bus that is being controlled is a slave. The FM32xx is always a slave device.

The bus protocol is controlled by transition states in the SDA and SCL signals. There are four conditions: Start, Stop, Data bit, and Acknowledge. The figure below illustrates the signal conditions that specify the four states. Detailed timing diagrams are shown in the Electrical Specifications section.

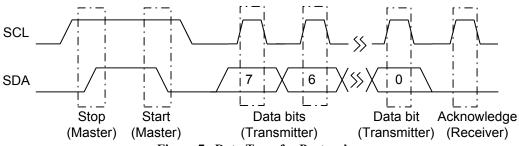


Figure 7. Data Transfer Protocol

#### **Start Condition**

A Start condition is indicated when the bus master drives SDA from high to low while the SCL signal is high. All read and write transactions begin with a Start condition. An operation in progress can be aborted by asserting a Start condition at any time. Aborting an operation using the Start condition will ready the FM32xx for a new operation.

If the power supply drops below the specified  $V_{TP}$  during operation, any 2-wire transaction in progress will be aborted and the system must issue a Start condition prior to performing another operation.

#### **Stop Condition**

A Stop condition is indicated when the bus master drives SDA from low to high while the SCL signal is high. All operations must end with a Stop condition. If an operation is pending when a stop is asserted, the operation will be aborted. The master must have control of SDA (not a memory read) in order to assert a Stop condition.

## Data/Address Transfer

All data transfers (including addresses) take place while the SCL signal is high. Except under the two conditions described above, the SDA signal should not change while SCL is high.

#### Acknowledge

The Acknowledge (ACK) takes place after the 8<sup>th</sup> data bit has been transferred in any transaction. During this state the transmitter must release the SDA bus to allow the receiver to drive it. The receiver drives the SDA signal low to acknowledge receipt of the byte. If the receiver does not drive SDA low, the condition is a No-Acknowledge (NACK) and the operation is aborted.

The receiver might NACK for two distinct reasons. First is that a byte transfer fails. In this case, the NACK ends the current operation so that the part can be addressed again. This allows the last byte to be recovered in the event of a communication error.

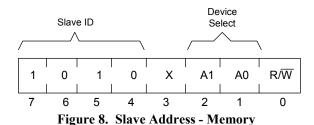
Second and most common, the receiver does not send an ACK to deliberately terminate an operation. For example, during a read operation, the FM32xx will continue to place data onto the bus as long as the receiver sends ACKs (and clocks). When a read operation is complete and no more data is needed, the receiver must NACK the last byte. If the receiver ACKs the last byte, this will cause the FM32xx to attempt to drive the bus on the next clock while the master is sending a new command such as a Stop.

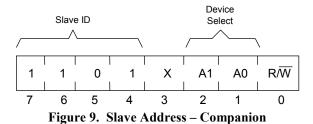
#### **Slave Address**

The first byte that the FM32xx expects after a Start condition is the slave address. As shown in figures below, the slave address contains the Slave ID, Device Select address, and a bit that specifies if the transaction is a read or a write.

The FM32xx has two Slave Addresses (Slave IDs) associated with two logical devices. To access the memory device, bits 7-4 should be set to 1010b. The other logical device within the FM32xx is the real-time clock and companion. To access this device, bits 7-4 of the slave address should be set to 1101b. A bus transaction with this slave address will not affect the memory in any way. The figures below illustrate the two Slave Addresses.

The Device Select bits allow multiple devices of the same type to reside on the 2-wire bus. The device select bits (bits 2-1) select one of four parts on a two-wire bus. They must match the corresponding value on the external address pins in order to select the device. Bit 0 is the read/write bit. A "1" indicates a read operation, and a "0" indicates a write operation.





#### Addressing Overview - Memory

After the FM32xx acknowledges the Slave Address, the master can place the memory address on the bus for a write operation. The address requires two bytes. This is true for all members of the family. Therefore the 4Kb and 16Kb configurations will be addressed differently from stand alone serial memories but the entire family will be upwardly compatible with no software changes.

The first is the MSB (upper byte). For a given density unused address bits are don't cares, but should be set to 0 to maintain upward compatibility.

Following the MSB is the LSB (lower byte) which contains the remaining eight address bits. The address is latched internally. Each access causes the latched address to be incremented automatically. The current address is the value that is held in the latch, either a newly written value or the address following the last access. The current address will be held as long as  $V_{\rm DD} > V_{\rm TP}$  or until a new value is written. Accesses to the clock do not affect the current memory address. Reads always use the current address. A random read address can be loaded by beginning a write operation as explained below.

After transmission of each data byte, just prior to the Acknowledge, the FM32xx increments the internal address. This allows the next sequential byte to be accessed with no additional addressing externally. After the last address is reached, the address latch will roll over to 0000h. There is no limit to the number of bytes that can be accessed with a single read or write operation.

## Addressing Overview - Companion

The Processor Companion operate in a similar manner to the memory, except that it uses only one byte of address. Addresses 00h to 18h correspond to special function registers. Attempting to load addresses above 18h is an illegal condition; the FM32xx will return a NACK and abort the 2-wire transaction.

#### **Data Transfer**

After the address information has been transmitted, data transfer between the bus master and the FM32xx begins. For a read, the FM32xx will place 8 data bits on the bus then wait for an ACK from the master. If the ACK occurs, the FM32xx will transfer the next byte. If the ACK is not sent, the FM32xx will end the read operation. For a write operation, the FM32xx will accept 8 data bits from the master then send an Acknowledge. All data transfer occurs MSB (most significant bit) first.

#### **Memory Write Operation**

All memory writes begin with a Slave Address, then a memory address. The bus master indicates a write operation by setting the slave address LSB to a 0. After addressing, the bus master sends each byte of data to the memory and the memory generates an Acknowledge condition. Any number of sequential bytes may be written. If the end of the address range is reached internally, the address counter will wrap to 0000h. Internally, the actual memory write occurs after the 8<sup>th</sup> data bit is transferred. It will be complete before the Acknowledge is sent. Therefore, if the user desires to abort a write without altering the memory contents, this should be done using a Start

or Stop condition prior to the 8<sup>th</sup> data bit. The figures below illustrate a single- and multiple-writes to

memory.

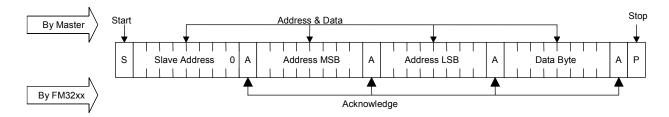


Figure 10. Single Byte Memory Write

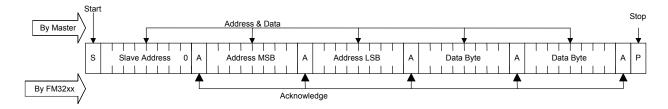


Figure 11. Multiple Byte Memory Write

#### **Memory Read Operation**

There are two types of memory read operations. They are current address read and selective address read. In a current address read, the FM32xx uses the internal address latch to supply the address. In a selective read, the user performs a procedure to first set the address to a specific value.

#### Current Address & Sequential Read

As mentioned above the FM32xx uses an internal latch to supply the address for a read operation. A current address read uses the existing value in the address latch as a starting place for the read operation. The system reads from the address immediately following that of the last operation.

To perform a current address read, the bus master supplies a slave address with the LSB set to 1. This indicates that a read operation is requested. After receiving the complete device address, the FM32xx will begin shifting data out from the current address on the next clock. The current address is the value held in the internal address latch.

Beginning with the current address, the bus master can read any number of bytes. Thus, a sequential read is simply a current address read with multiple byte transfers. After each byte the internal address counter will be incremented.

Each time the bus master acknowledges a byte, this indicates that the FM32xx should read out the next sequential byte.

There are four ways to terminate a read operation. Failing to properly terminate the read will most likely create a bus contention as the FM32xx attempts to read out additional data onto the bus. The four valid methods follow.

- 1. The bus master issues a NACK in the 9<sup>th</sup> clock cycle and a Stop in the 10<sup>th</sup> clock cycle. This is illustrated in the diagrams below and is preferred.
- 2. The bus master issues a NACK in the 9<sup>th</sup> clock cycle and a Start in the 10<sup>th</sup>.
- 3. The bus master issues a Stop in the 9<sup>th</sup> clock cycle.
- 4. The bus master issues a Start in the 9<sup>th</sup> clock cycle.

If the internal address reaches the top of memory, it will wrap around to 0000h on the next read cycle. The figures below show the proper operation for current address reads.

#### Selective (Random) Read

There is a simple technique that allows a user to select a random address location as the starting point for a read operation. This involves using the first

three bytes of a write operation to set the internal address followed by subsequent read operations.

To perform a selective read, the bus master sends out the slave address with the LSB set to 0. This specifies a write operation. According to the write protocol, the bus master then sends the address bytes that are loaded into the internal address latch. After the FM32xx acknowledges the address, the bus master issues a Start condition. This simultaneously aborts the write operation and allows the read command to be issued with the slave address LSB set to a 1. The operation is now a read from the current address. Read operations are illustrated below.

### **Companion Write Operation**

All Companion writes operate in a similar manner to memory writes. The distinction is that a different device ID is used and only one byte of address is needed instead of two. Figure 15 illustrates a single byte write to this device.

#### **Companion Read Operation**

As with writes, a read operation begins with the Slave Address. To perform a register read, the bus

master supplies a Slave Address with the LSB set to 1. This indicates that a read operation is requested. After receiving the complete Slave Address, the FM32xx will begin shifting data out from the current register address on the next clock. Auto-increment operates for the special function registers as with the memory address. A current address read for the registers look exactly like the memory except that the device ID is different.

The FM32xx contains two separate address registers, one for the memory address and the other for the register address. This allows the contents of one address register to be modified without affecting the current address of the other register. For example, this would allow an interrupted read to the memory while still providing fast access to a companion register. A subsequent memory read will then continue from the memory address where it previously left off, without requiring the load of a new memory address. However, a write sequence always requires an address to be supplied.

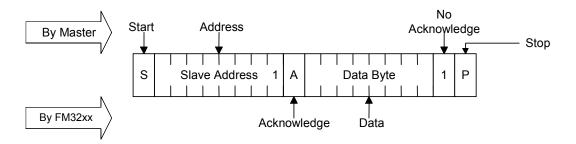


Figure 12. Current Address Memory Read

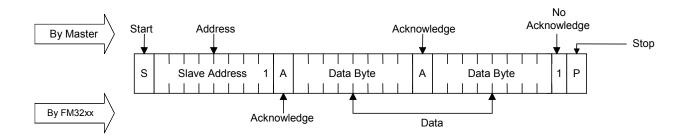


Figure 13. Sequential Memory Read

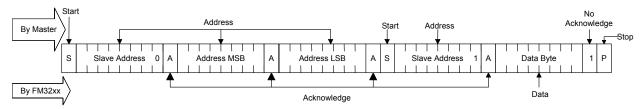


Figure 14. Selective (Random) Memory Read

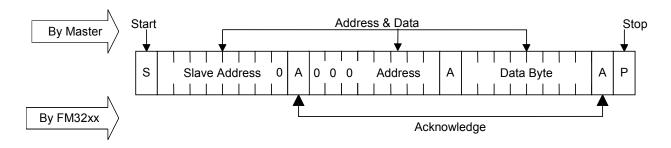


Figure 15. Byte Register Write

\* Although not required, it is recommended that A5-A7 in the Register Address byte are zeros in order to preserve compatibility with future devices.

## Addressing FRAM Array in the FM32xx Family

The FM32xx family includes 256Kb, 64Kb, 16Kb, and 4Kb memory densities. The following 2-byte address field is shown for each density.

Table 4. Two-Byte Memory Address

Part #		1 <sup>st</sup> Address Byte									$2^{nd}$	Addr	ess B	yte		
FM32256	х	A14	A13	A12	A11	A10	A9	A8	A7	A6	A5	A4	A3	A2	A1	A0
FM3264	х	Х	Х	A12	A11	A10	A9	A8	A7	A6	A5	A4	A3	A2	A1	A0
FM3216	х	х	Х	Х	Х	A10	A9	A8	A7	A6	A5	A4	A3	A2	A1	A0
FM3204	х	Х	Х	Х	Х	Х	х	A8	A7	A6	A5	A4	A3	A2	A1	A0

## **Electrical Specifications**

**Absolute Maximum Ratings** 

Symbol	Description	Ratings
$ m V_{DD}$	Power Supply Voltage with respect to V <sub>SS</sub>	-1.0V to +7.0V
$V_{\rm IN}$	Voltage on any signal pin with respect to V <sub>SS</sub>	-1.0V to $+7.0V$ * and
		$V_{IN} \le V_{DD} + 1.0V **$
$V_{\mathrm{BAK}}$	Backup Supply Voltage	-1.0V to +4.5V
$T_{STG}$	Storage Temperature	-55°C to $+ 125$ °C
$T_{LEAD}$	Lead Temperature (Soldering, 10 seconds)	260° C
$V_{\mathrm{ESD}}$	Electrostatic Discharge Voltage	
	- Human Body Model (JEDEC Std JESD22-A114-B)	4kV
	- Charged Device Model (JEDEC Std JESD22-C101-A)	1kV
	- Machine Model (JEDEC Std JESD22-A115-A)	250V
	Package Moisture Sensitivity Level	MSL-1

<sup>\*</sup> PFI input voltage must not exceed 4.5V.

**DC Operating Conditions** ( $T_A = -40^{\circ} \text{ C to} + 85^{\circ} \text{ C}$ ,  $V_{DD} = 2.7 \text{ V to} 5.5 \text{ V}$  unless otherwise specified)

Symbol	Parameter	Min	Тур	Max	Units	Notes
$V_{\mathrm{DD}}$	Main Power Supply	2.7		5.5	V	7
$I_{DD}$	V <sub>DD</sub> Supply Current					1
	@ SCL = 100 kHz			500	μΑ	
	@ SCL = $400  kHz$			900	μΑ	
	@ SCL = 1 MHz			1500	μΑ	
$I_{SB}$	Standby Current					2
	For $V_{DD} < 5.5V$			150	μΑ	
	For $V_{DD} < 3.6V$			120	μA	
$V_{BAK}$	Backup Supply Voltage	2.0	3.0	3.75	V	9
$I_{BAK}$	Backup Supply Current			1	μΑ	4
$I_{BAKTC}$	Trickle Charge Current	5		25	μΑ	10
$V_{TP0}$	$V_{DD}$ Trip Point Voltage, VTP(1:0) = 00b	2.55	2.6	2.70	V	5
$V_{TP1}$	$V_{DD}$ Trip Point Voltage, VTP(1:0) = 01b	2.85	2.9	3.00	V	5
$V_{TP2}$	$V_{DD}$ Trip Point Voltage, VTP(1:0) = 10b	3.80	3.9	4.00	V	5
$V_{TP3}$	$V_{DD}$ Trip Point Voltage, VTP(1:0) = 11b	4.25	4.4	4.50	V	5
$V_{RST}$	$V_{DD}$ for valid /RST @ $I_{OL}$ = 80 $\mu$ A at $V_{OL}$					6
	$V_{BAK} > V_{BAK}$ min	0			V	
	$V_{BAK} < V_{BAK}$ min	1.6			V	
$I_{LI}$	Input Leakage Current			±1	μΑ	3
$I_{LO}$	Output Leakage Current			±1	μΑ	3
$V_{\mathrm{IL}}$	Input Low Voltage					
	All inputs except those listed below	-0.3		$0.3~\mathrm{V_{DD}}$	V	8
	CNT1-2 battery backed (V <sub>DD</sub> < 2.5V)	-0.3		0.5	V	
	$CNT1-2 (V_{DD} > 2.5V)$	-0.3		0.8	V	
$V_{\mathrm{IH}}$	Input High Voltage					
	All inputs except those listed below	$0.7~\mathrm{V_{DD}}$		$V_{\rm DD} + 0.3$	V	
	PFI (comparator input)	- 0.5		3.75	V	
	CNT1-2 battery backed ( $V_{DD} < 2.5V$ )	$V_{BAK} - 0.5$		$V_{BAK} + 0.3$	V	
<b>1</b> 7	$\frac{\text{CNT1-2 V}_{\text{DD}} > 2.5\text{V}}{Control Model No. 100 Model No. 100$	$0.7  \mathrm{V}_{\mathrm{DD}}$		$V_{DD} + 0.3$	V	
V <sub>OL</sub>	Output Low Voltage (I <sub>OL</sub> = 3 mA)	-		0.4	V	
V <sub>OH</sub>	Output High Voltage (I <sub>OH</sub> = -2 mA)	2.4		- 400	V	
$R_{RST}$	Pull-up resistance for /RST inactive	50		400	ΚΩ	

<sup>\*\*</sup> The  ${}^{\'}V_{\rm IN} < V_{\rm DD} + 1.0 V$ " restriction does not apply to the SCL and SDA inputs which do not employ a diode to  $V_{\rm DD}$ . Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only, and the functional operation of the device at these or any other conditions above those listed in the operational section of this specification is not implied. Exposure to absolute maximum ratings conditions for extended periods may affect device reliability.

Continued »

**DC Operating Conditions, continued** ( $T_A = -40^{\circ} \text{ C to} + 85^{\circ} \text{ C}$ ,  $V_{DD} = 2.7 \text{ V to} 5.5 \text{ V}$  unless otherwise specified)

Symbol	Parameter	Min	Тур	Max	Units	Notes
$R_{IN}$	Input Resistance (pulldown)					
	A1-A0 for $V_{IN} = V_{IL}$ max	20			ΚΩ	
	A1-A0 for $V_{IN} = V_{IH} \min$	1			$M\Omega$	
V <sub>PFI</sub>	Power Fail Input Reference Voltage	1.175	1.20	1.225	V	
$V_{HYS}$	Power Fail Input (PFI) Hysteresis (Rising)		-	100	mV	

#### Notes

- SCL toggling between  $V_{DD}$ -0.3V and  $V_{SS}$ , other inputs  $V_{SS}$  or  $V_{DD}$ -0.3V.
- All inputs at  $V_{SS}$  or  $V_{DD}$ , static. Stop command issued. 2.
- $V_{IN}$  or  $V_{OUT} = V_{SS}$  to  $V_{DD}$ . Does not apply to A0, A1, PFI, or /RST pins.  $V_{BAK} = 3.0V$ ,  $V_{DD} < 2.4V$ , CNT1-2 at  $V_{BAK}$ . 3.
- 5. /RST is asserted low when  $V_{DD} \le V_{TP}$ .
- The minimum V<sub>DD</sub> to guarantee the level of /RST remains a valid V<sub>OL</sub> level.
- Full complete operation. Supervisory circuits operate to lower voltages as specified.
- Includes /RST input detection of external reset condition to trigger driving of /RST signal by FM32xx.
- The VBAK trickle charger automatically regulates the maximum voltage on this pin for capacitor backup applications.
- 10.  $V_{BAK}$  will source current when trickle charge is enabled (VBC bit=1),  $V_{DD} > V_{BAK}$ , and  $V_{BAK} < V_{BAK}$  max.

AC Parameters  $(T - 40^{\circ} C \text{ to} + 85^{\circ} C \text{ V}) = 2.7 \text{V to} 5.5 \text{V} C = 100 \text{ nE unless otherwise specified})$ 

Symbol	Parameter Min Max Min Max Min		Min	Max	Units	Notes			
$f_{SCL}$	SCL Clock Frequency	0	100	0	400	0	1000	kHz	
$t_{LOW}$	Clock Low Period	4.7		1.3		0.6		μs	
$t_{HIGH}$	Clock High Period	4.0		0.6		0.4		μs	
$t_{AA}$	SCL Low to SDA Data Out Valid		3		0.9		0.55 με		
$t_{ m BUF}$	Bus Free Before New Transmission	4.7		1.3		0.5		μs	
t <sub>HD:STA</sub>	Start Condition Hold Time	4.0		0.6		0.25		μs	
t <sub>SU:STA</sub>	Start Condition Setup for Repeated	4.7		0.6		0.25		μs	
	Start							·	
$t_{\text{HD:DAT}}$	Data In Hold Time	0		0		0		ns	
t <sub>SU:DAT</sub>	Data In Setup Time	250		100		100		ns	
$t_R$	Input Rise Time		1000		300		300	ns	1
$t_{\rm F}$	Input Fall Time		300		300		100	ns	1
t <sub>SU:STO</sub>	Stop Condition Setup Time	4.0		0.6		0.25		μs	
$t_{\mathrm{DH}}$	Data Output Hold (from SCL @ VIL)	0		0		0		ns	
$t_{SP}$	Noise Suppression Time Constant on SCL, SDA		50		50		50	ns	

All SCL specifications as well as start and stop conditions apply to both read and write operations.

Capacitance ( $T_A = 25^{\circ} \text{ C}$ , f=1.0 MHz,  $V_{DD} = 3.0 \text{V}$ )

Symbol	Parameter	Тур	Max	Units	Notes
$C_{IO}$	Input/Output Capacitance	-	8	pF	1

#### **Notes**

This parameter is characterized but not tested.

**Data Retention** ( $T_A = -40^{\circ} \text{ C to} + 85^{\circ} \text{ C}, V_{DD} = 2.7 \text{ V to } 5.5 \text{ V}$ )

Parameter	Min	Units	Notes
Data Retention	10	Years	

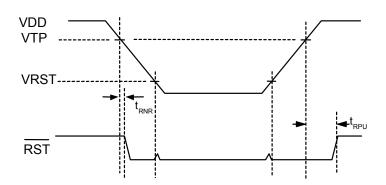
**Supervisor Timing** ( $T_A = -40^{\circ} \text{ C to} + 85^{\circ} \text{ C}, V_{DD} = 2.7 \text{ V to } 5.5 \text{ V}$ )

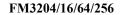
Symbol	Parameter	Min	Max	Units	Notes
$t_{ m RPU}$	/RST Active (low) after V <sub>DD</sub> >V <sub>TP</sub>	100	200	ms	
$t_{RNR}$	$V_{DD} < V_{TP}$ Noise Immunity	10	25	μs	1
$t_{VR}$	V <sub>DD</sub> Rise Time	50	-	μs/V	1,2
$t_{VF}$	V <sub>DD</sub> Fall Time	100	-	μs/V	1,2
$t_{\mathrm{WDP}}$	Pulse Width of /RST for Watchdog Reset	100	200	ms	
$t_{ m WDOG}$	Timeout of Watchdog	$t_{ m DOG}$	2*t <sub>DOG</sub>	ms	3
$f_{CNT}$	Frequency of Event Counters	0	10	MHz	

### Notes

- This parameter is characterized but not tested.
- Slope measured at any point on  $V_{DD}$  waveform.  $t_{DOG}$  is the programmed time in register 0Ah,  $V_{DD} > V_{TP}$  and  $t_{RPU}$  satisfied.

## /RST Timing





### **AC Test Conditions**

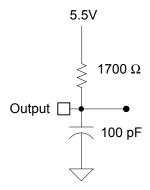
Input Pulse Levels  $0.1 V_{DD}$  to  $0.9 V_{DD}$ 

Input rise and fall times 10 ns
Input and output timing levels 0.5 V<sub>DD</sub>

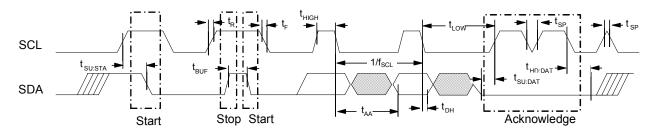
### **Diagram Notes**

All start and stop timing parameters apply to both read and write cycles. Clock specifications are identical for read and write cycles. Write timing parameters apply to slave address, word address, and write data bits. Functional relationships are illustrated in the relevant data sheet sections. These diagrams illustrate the timing parameters only.

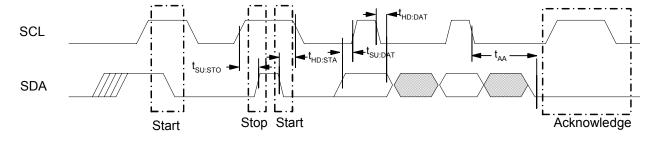
## **Equivalent AC Load Circuit**



## **Read Bus Timing**



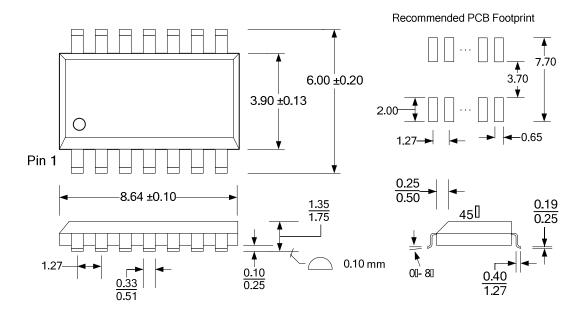
## Write Bus Timing



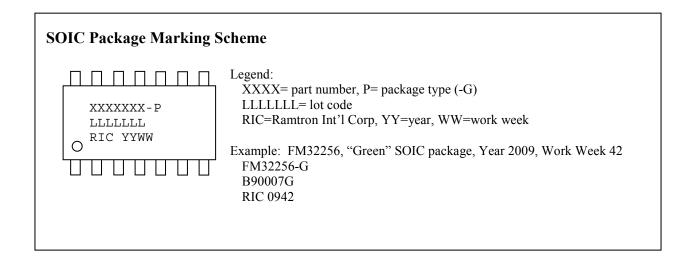
FM3204/16/64/256

## **Mechanical Drawing**

## 14-pin SOIC (JEDEC Standard MS-012 variation AB)



Refer to JEDEC MS-012 for complete dimensions and notes. All dimensions in millimeters.



FM3204/16/64/256

# **Revision History**

Revision	Date	Summary
0.2	5/22/03	Initial release.
0.21	11/25/03	Fixed package drawing dimensions.
1.0	3/30/04	Changed product status to Preliminary. Added $V_{TP}$ and $V_{PFI}$ parameters in DC Operating table. Changed $V_{HYS}$ limits. Added "green" package.
2.0	10/25/04	Changed to Pre-Production status. Added text to Trickle Charger section. Improved spec limits on V <sub>TP</sub> , V <sub>PFI</sub> , and V <sub>HYS</sub> parameters and changed V <sub>IH</sub> max limits in DC Operating table. Added companion register table with default values. Added Package Marking Scheme and board footprint. Devices marked with Date Codes 0440 and higher comply with the revision of the datasheet.
2.1	12/8/04	Changed description of POR flag and manual reset (pg. 5, 10). Added notes to Absolute Maximum Ratings.
2.2	10/5/05	Rewrote section on battery backup. Added comment about unused CNT pins.
2.3	10/2/06	Removed -S packaging option which is Not Recommended for New Designs. Added ESD and MSL ratings which are valid for Date Codes 0440 and higher.
2.4	3/18/2008	Not recommended for new designs. As an alternative, use FM3127xB for 5V designs or FM31L27xB for 3V designs.
3.0	3/30/2010	Changed to Production status. These products are no longer Not Recommended for New Designs (NRND). Updated ESD ratings. Updated lead temperature rating in Abs Max table. Removed battery insertion sequence text (p. 6). The sequence is no longer necessary for devices with date codes after 0701.
3.1	7/27/2010	Removed text indicating that a manual reset sets the POR flag.